TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

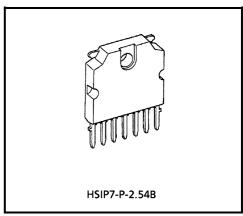
TA8427K

POWER AMPLIFIER FOR DRIVING A DEFLECTION CIRCUIT OF A COLOR TELEVISION

TA8427K is a power amplifier for driving a deflection circuit of a large and medium screen size color television. TA8427K is available for constructing a stable deflection circuit with small number parts in an application with a single chip signal processing IC TA8879N.

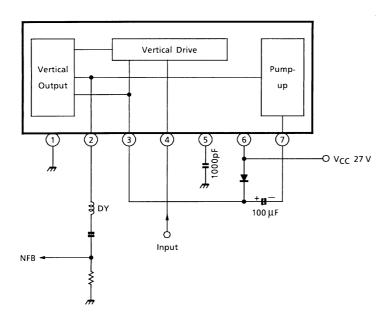
FEATURES

- Large output current ; 2.2A_{p-p} (Max.)
- Small power dissipation with a pump-up circuit
- Small number external parts



Weight: 2.2g (Typ.)

BLOCK DIAGRAM



TERMINAL NAME

- 1. GND
- 2. Vertical Output
- 3. Pump-up Power Supply
- 4. Input
- 5. Phase Compensation
- 6. Power Supply
- 7. Pump-up Output

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damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

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[•] The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

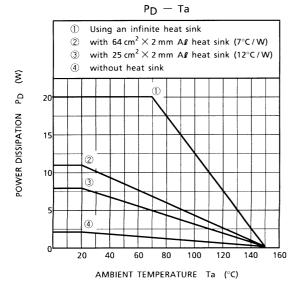


MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	V _{CC}	30	V
Pump-up Power Supply Voltage	V _{Vt}	60	V
Terminal Voltage	E _{in}	GND -0.3 ~ V _{Vt} +0.3	٧
Input Signal Voltage	e _{in}	0 ~ 1.2	V
Deflection Current	id	±1.5 (Note 1:)	Α
Power Dissipation	P _D	20 (Note 2:)	W
Operating Temperature	T _{opr}	-20 ~ 85	°C
Storage Temperature	T _{stg}	− 55 ~ 150	°C

Note 1: Power on time; 2ms, $V_{CEO} = 60V$

Note 2: Using an infinite heat sink



Thermal resistance $\theta_{jc} = 4^{\circ}C/W$

RECOMMENDED OPERATING CONDITION

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Power Supply	V _{CC}	_	27	29	V
Deflection Output Current	I _{2p-p}	_	-	2.2	A _{p-p}

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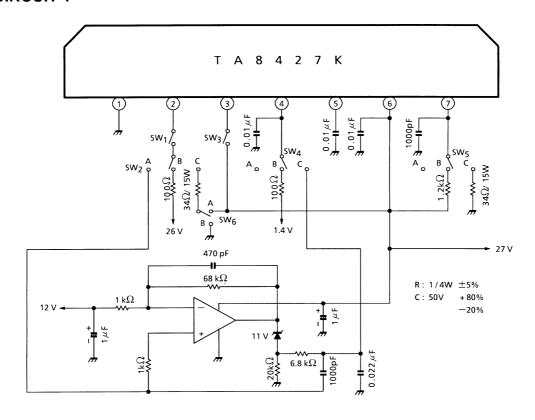


ELECTRICAL CHARACTERISTICS (Ta = 25°C, V_{CC} = 24V)

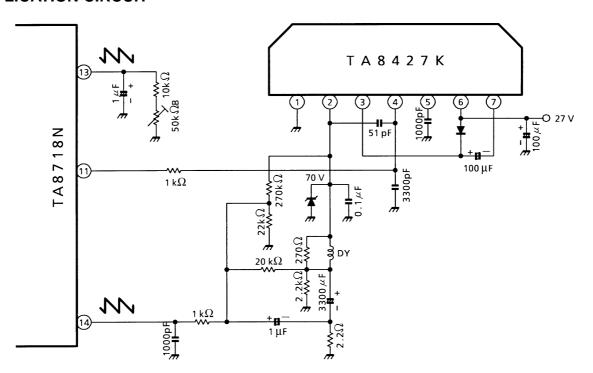
CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Saturation Voltage Of The Vertical Output Transistor (1)	V _{v (sat) 1}	1	Note 1:	0.3	0.5	1.0	٧
Saturation Voltage Of The Vertical Output Transistor (2)	V _{v (sat) 2}	1	Note 2:	1.0	1.8	3.6	٧
Saturation Voltage Of The Pump-up Output Transistor (1)	V _{p (sat) 1}	1	Note 3:	1.0	2.0	3.0	٧
Saturation Voltage Of The Pump-up Output Transistor (2)	V _{p (sat) 2}	1	Note 4:	0.2	0.8	1.6	V
Output Current With No Input	I _b	1	1 Note 5:	_	26.0	_	mA
Center Output Voltage	V _{center}			10.0	12.0	14.0	V

- Note 1: SW_1 : ON, SW_2 : C, SW_3 : ON, SW_4 : B, SW_5 : A, SW_6 : A Measure the voltage of pin 2.
- Note 2: SW_1 : ON, SW_2 : C, SW_3 : ON, SW_4 : A, SW_5 : A, SW_6 : B Measure the voltage of pin 2, V_2 . V_V (sat) 2 = V_{CC} V_2
- Note 3: SW_1 : ON, SW_2 : B, SW_3 : OFF, SW_4 : A, SW_5 : C, SW_6 : A Measure the voltage of pin 7, V_7 . V_P (sat) 1 = V_{CC} V_7
- Note 4: $SW_1: OFF, SW_2: C, SW_3: OFF, SW_4: A, SW_5: B, SW_6: B$ Measure the voltage of pin 7.
- Note 5: SW_1 : ON, SW_2 : A, SW_3 : ON, SW_4 : C, SW_5 : A, SW_6 : B Measure the sink current into pin 3. Measure the voltage of pin 2.

TEST CIRCUIT 1



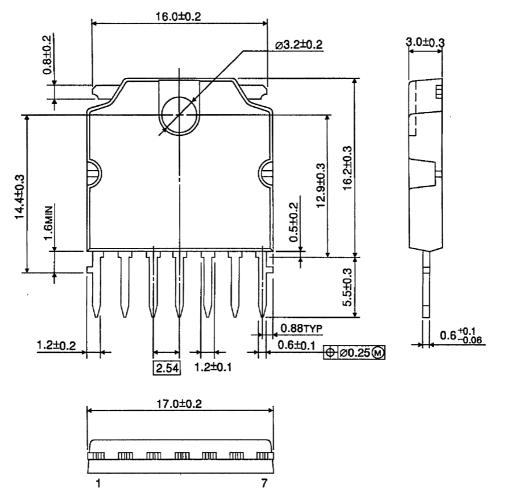
APPLICATION CIRCUIT





PACKAGE DIMENSIONS

Unit: mm HSIP7-P-2.54B



Weight: 2.2g (Typ.)